

8K Microwire Compatible Serial EEPROM

Device Selection Table

Part Number	Vcc Range	ORG Pin	PE Pin	Word Size	Temp Ranges	Packages
93AA76A	1.8-5.5	No	No	8-bit	I	OT
93AA76B	1.8-5-5	No	No	16-bit	I	OT
93LC76A	2.5-5.5	No	No	8-bit	I, E	OT
93LC76B	2.5-5.5	No	No	16-bit	I, E	OT
93C76A	4.5-5.5	No	No	8-bit	I, E	OT
93C76B	4.5-5.5	No	No	16-bit	I, E	OT
93AA76C	1.8-5.5	Yes	Yes	8 or 16-bit	I	P, SN, ST, MS
93LC76C	2.5-5.5	Yes	Yes	8 or 16-bit	I, E	P, SN, ST, MS
93C76C	4.5-5.5	Yes	Yes	8 or 16-bit	I, E	P, SN, ST, MS

Features

- Low-power CMOS technology
- ORG pin to select word size for '76C' version
- 1024 x 8-bit organization 'A' devices (no ORG)
- 512 x 16-bit organization 'B' devices (no ORG)
- Program Enable pin to write-protect the entire array (except on SOT-23 packages)
- Self-timed ERASE/WRITE cycles (including auto-erase)
- Automatic ERAL before WRAL
- Power-on/off data protection circuitry
- Industry standard 3-wire serial I/O
- Device Status signal (READY/BUSY)
- Sequential READ function
- 1,000,000 E/W cycles
- Data retention > 200 years
- Temperature ranges supported:
 - Industrial (I) -40°C to +85°C

```
- Automotive (E) -40°C to +125°C
```

Pin Function Table

Name	Function			
CS	Chip Select			
CLK	Serial Data Clock			
DI	Serial Data Input			
DO	Serial Data Output			
Vss	Ground			
PE	Program Enable			
ORG	Memory Configuration			
Vcc	Power Supply			

Description

The Microchip Technology Inc. 93XX76A/B/C devices are 8K bit, low-voltage, serial Electrically Erasable PROMs (EEPROM). Word-selectable devices such as the 93XX76C are dependent upon external logic levels driving the ORG pin to set word size. For dedicated 8-bit communication, the 93XX76A devices are available, while the 93XX76B devices provide dedicated 16-bit communication, available on SOT-23 devices only. A Program Enable (PE) pin allows the user to write-protect the entire memory array. Advanced CMOS technology makes these devices ideal for low-power, nonvolatile memory applications. The 93XX Series is available in standard packages including 8-lead PDIP and SOIC, and advanced packaging including 8-lead MSOP, 6-lead SOT-23, and 8-lead TSSOP. Pb-free (Pure Matte Sn) finish is also available.

Package Types (not to scale)

	P/SOIC SN)	SOT-23 (OT)
CS [] CLK [2 DI []3 DO []4	8⊒Vcc 7⊒PE 6⊒ORG 5⊒Vss	DOCT ¹ 65Vcc VssCf ² 55CCS DICT ³ 455CLK
	TSSOP (ST,	
	CS 년 10 CLK 년 2 DI 년 3 DO 년 4	8 코 Vcc 7 코 PE 6 코 ORG 5 코 Vss

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (†)

Vcc	7.0V
All inputs and outputs w.r.t. Vss	-0.6V to Vcc +1.0V
Storage temperature	65°C to +150°C
Ambient temperature with power applied	40°C to +125°C
ESD protection on all pins	≥4 kV

† NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: DC CHARACTERISTICS

	All parameters apply over the specified ranges unless otherwise noted.			Vcc = 1.8V to 5.5V Industrial (I): TA = -40°C to +85°C Automotive (E): TA = -40°C to +125°C						
Param. No.	Symbol	Parameter	Min	Тур	Max	Units	Conditions			
D1	Viн1 Viн2	High-level input voltage	2.0 0.7 Vcc		Vcc +1 Vcc +1	V V	Vcc ≥ 2.7V Vcc < 2.7V			
D2	Vi∟1 Vi∟2	Low-level input voltage	-0.3 -0.3		0.8 0.2 Vcc	V V	Vcc ≥ 2.7V Vcc < 2.7V			
D3	Vol1 Vol2	Low-level output voltage	_		0.4 0.2	V V	IOL = 2.1 mA, VCC = 4.5V $IOL = 100 \mu A, VCC = 2.5V$			
D4	Vон1 Vон2	High-level output voltage	2.4 Vcc - 0.2		_	V V	IOH = -400 μA, VCC = 4.5V IOH = -100 μA, VCC = 2.5V			
D5	ILI	Input leakage current	—		±1	μA	VIN = VSS to VCC			
D6	Ilo	Output leakage current	—		±1	μA	VOUT = VSS to VCC			
D7	CIN, COUT	Pin capacitance (all inputs/ outputs)	—	-	7	pF	VIN/VOUT = 0V (Note 1) TA = 25°C, FCLK = 1 MHz			
D8	ICC write	Write current	_	 500	3	mA μA	FCLK = 3 MHz, VCC = 5.5V FCLK = 2 MHz, VCC = 2.5V			
D9	ICC read	Read current		— — 100	1 500 —	mΑ μΑ μΑ	FCLK = 3 MHz, VCC = 5.5V FCLK = 2 MHz, VCC = 3.0V FCLK = 2 MHz, VCC = 2.5V			
D10	Iccs	Standby current			1 5	μΑ μΑ	I – Temp E – Temp CLK = Cs = 0V ORG = DI = Vss or Vcc (Note 2) (Note 3)			
D11	VPOR	Vcc voltage detect 93AA76A/B/C, 93LC76A/B/C 93C76A/B/C		1.5V 3.8V		V V	(Note 1)			

Note 1: This parameter is periodically sampled and not 100% tested.

2: ORG pin not available on 'A' or 'B' versions.

3: READY/BUSY status must be cleared from DO, see Section 3.4 "Data Out (DO)".

TABLE 1-2: AC CHARACTERISTICS

All parameters apply over the specified ranges unless otherwise noted.			Vcc = $1.8V$ to $5.5V$ Industrial (I): TA = -40° C to $+85^{\circ}$ C Automotive (E): TA = -40° C to $+125^{\circ}$ C						
Param. No.	Symbol	Parameter	Min	Мах	Units	Conditions			
A1	FCLK	Clock frequency	-	3 2 1	MHz MHz MHz	4.5V ≤ Vcc < 5.5V 2.5V ≤ Vcc < 4.5V 1.8V ≤ Vcc < 2.5V			
A2	Тскн	Clock high time	200 250 450	—	ns ns ns	4.5V ≤ Vcc < 5.5V 2.5V ≤ Vcc < 4.5V 1.8V ≤ Vcc < 2.5V			
A3	TCKL	Clock low time	100 200 450	—	ns ns ns	4.5V ≤ Vcc < 5.5V 2.5V ≤ Vcc < 4.5V 1.8V ≤ Vcc < 2.5V			
A4	Tcss	Chip Select setup time	50 100 250	—	ns ns ns	4.5V ≤ Vcc < 5.5V 2.5V ≤ Vcc < 4.5V 1.8V ≤ Vcc < 2.5V			
A5	Тсѕн	Chip Select hold time	0	_	ns	1.8V ≤ Vcc < 5.5V			
A6	TCSL	Chip Select low time	250	—	ns	1.8V ≤ VCC < 5.5V			
A7	TDIS	Data input setup time	50 100 250	—	ns ns ns	4.5V ≤ Vcc < 5.5V 2.5V ≤ Vcc < 4.5V 1.8V ≤ Vcc < 2.5V			
A8	Тон	Data input hold time	50 100 250	_	ns ns ns	4.5V ≤ VCC < 5.5V 2.5V ≤ VCC < 4.5V 1.8V ≤ VCC < 2.5V			
A9	TPD	Data output delay time		100 250 400	ns ns ns	4.5V ≤ VCC < 5.5V, CL = 100 pF 2.5V ≤ VCC < 4.5V, CL = 100 pF 1.8V ≤ VCC < 2.5V, CL = 100 pF			
A10	Tcz	Data output disable time	-	100 200	ns ns	4.5V ≤ Vcc < 5.5V, (Note 1) 1.8V ≤ Vcc < 4.5V, (Note 1)			
A11	Tsv	Status valid time	-	200 300 500	ns ns ns	4.5V ≤ Vcc < 5.5V, CL = 100 pF 2.5V ≤ Vcc < 4.5V, CL = 100 pF 1.8V ≤ Vcc < 2.5V, CL = 100 pF			
A12	Twc	Program cycle time	_	5	ms	Erase/Write mode (AA and LC versions)			
A13	Twc		—	2	ms	Erase/Write mode (93C versions)			
A14	TEC			6	ms	ERAL mode, $4.5V \le VCC \le 5.5V$			
A15	TWL		—	15	ms	WRAL mode, $4.5V \le VCC \le 5.5V$			
A16	_	Endurance	1M		cycles	25°C, Vcc = 5.0V, (Note 2)			

Note 1: This parameter is periodically sampled and not 100% tested.

2: This application is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance[™] Model which may be obtained from www.microchip.com.

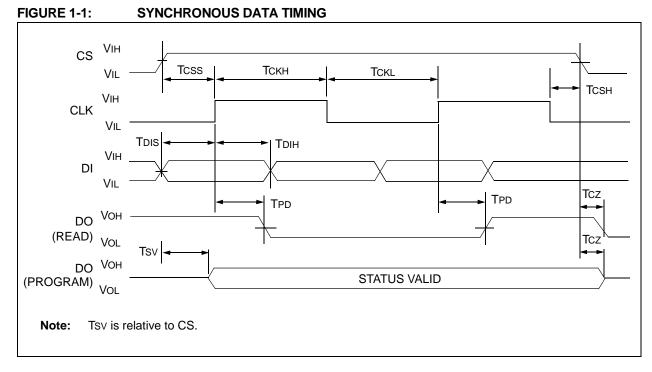


TABLE 1-3: INSTRUCTION SET FOR X 16 ORGANIZATION (93XX76B OR 93XX76C WITH ORG = 1)

Instruction	SB	Opcode					Add	ress					Data In	Data Out	Req. CLK Cycles
READ	1	10	Х	A8	A7	A6	A5	A4	A3	A2	A1	A0		D15 – D0	29
EWEN	1	00	1	1	Х	Х	Х	Х	Х	Х	Х	Х	_	HIGH-Z	13
ERASE	1	11	Х	A8	A7	A6	A5	A4	A3	A2	A1	A0	_	(RDY/BSY)	13
ERAL	1	00	1	0	Х	Х	Х	Х	Х	Х	Х	Х	_	(RDY/BSY)	13
WRITE	1	01	Х	A8	A7	A6	A5	A4	A3	A2	A1	A0	D15 – D0	(RDY/BSY)	29
WRAL	1	00	0	1	Х	Х	Х	Х	Х	Х	Х	Х	D15 – D0	(RDY/BSY)	29
EWDS	1	00	0	0	Х	Х	Х	Х	Х	Х	Х	Х		HIGH-Z	13

TABLE 1-4: INSTRUCTION SET FOR X 8 ORGANIZATION (93XX76A OR 93XX76C WITH ORG = 0)

Instruction	SB	Opcode					Ac	dre	SS					Data In	Data Out	Req. CLK Cycles
READ	1	10	Х	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0		D7 – D0	22
EWEN	1	00	1	1	Х	Х	Х	Х	Х	Х	Х	Х	Х		HIGH-Z	14
ERASE	1	11	Х	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	_	(RDY/BSY)	14
ERAL	1	00	1	0	Х	Х	Х	Х	Х	Х	Х	Х	Х		(RDY/BSY)	14
WRITE	1	01	Х	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	D7 – D0	(RDY/BSY)	22
WRAL	1	00	0	1	Х	Х	Х	Х	Х	Х	Х	Х	Х	D7 – D0	(RDY/BSY)	22
EWDS	1	00	0	0	Х	Х	Х	Х	Х	Х	Х	Х	Х		HIGH-Z	14

2.0 FUNCTIONAL DESCRIPTION

When the ORG* pin is connected to Vcc, the (x16) organization is selected. When it is connected to ground, the (x8) organization is selected. Instructions, addresses and write data are clocked into the DI pin on the rising edge of the clock (CLK). The DO pin is normally held in a HIGH-Z state except when reading data from the device, or when checking the READY/BUSY status during a programming operation. The READY/BUSY status can be verified during an Erase/Write operation by polling the DO pin; DO low indicates that programming is still in progress, while DO high indicates the device is ready. DO will enter the HIGH-Z state on the falling edge of CS.

2.1 Start Condition

The Start bit is detected by the device if CS and DI are both high with respect to the positive edge of CLK for the first time.

Before a Start condition is detected, CS, CLK and DI may change in any combination (except to that of a Start condition), without resulting in any device operation (READ, WRITE, ERASE, EWEN, EWDS, ERAL or WRAL). As soon as CS is high, the device is no longer in Standby mode.

An instruction following a Start condition will only be executed if the required opcode, address and data bits for any particular instruction are clocked in.

2.2 Data In/Data Out (DI/DO)

It is possible to connect the Data In and Data Out pins together. However, with this configuration it is possible for a "bus conflict" to occur during the "dummy zero" that precedes the read operation, if A0 is a logic highlevel. Under such a condition the voltage level seen at Data Out is undefined and will depend upon the relative impedances of Data Out and the signal source driving A0. The higher the current sourcing capability of the driver, the higher the voltage at the Data Out pin. In order to limit this current, a resistor should be connected between DI and DO.

2.3 Data Protection

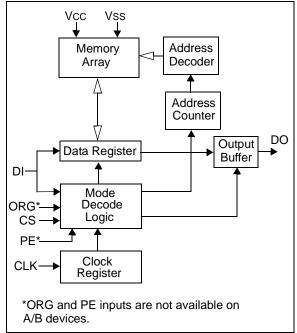
All modes of operation are inhibited when Vcc is below a typical voltage of 1.5V for '93AA' and '93LC' devices or 3.8V for '93C' devices.

The EWEN and EWDS commands give additional protection against accidentally programming during normal operation.

Note: For added protection, an EWDS command should be performed after every write operation.

After power-up, the device is automatically in the EWDS mode. Therefore, an EWEN instruction must be performed before the initial ERASE or WRITE instruction can be executed.

Block Diagram

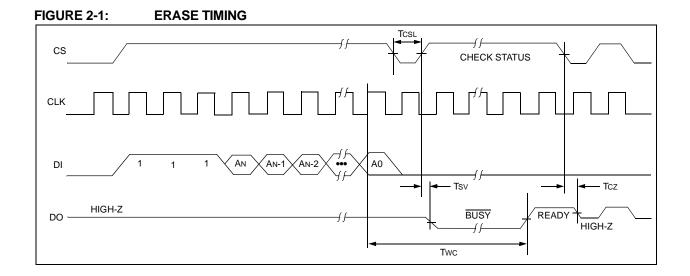


2.4 ERASE

The ERASE instruction forces all data bits of the specified address to the logical '1' state. The rising edge of CLK before the last address bit initiates the write cycle.

The DO pin indicates the READY/BUSY status of the device if CS is brought high after a minimum of 250 ns low (TCSL). DO at logical '0' indicates that programming is still in progress. DO at logical '1' indicates that the register at the specified address has been erased and the device is ready for another instruction.

Note: Issuing a Start bit and then taking CS low will clear the READY/BUSY status from DO.



2.5 **ERASE ALL (ERAL)**

The Erase All (ERAL) instruction will erase the entire memory array to the logical '1' state. The ERAL cycle is identical to the ERASE cycle, except for the different opcode. The ERAL cycle is completely self-timed. The rising edge of CLK before the last data bit initiates the write cycle. Clocking of the CLK pin is not necessary after the device has entered the ERAL cycle.

The DO pin indicates the READY/BUSY status of the device, if CS is brought high after a minimum of 250 ns low (TCSL).

Note: Issuing a Start bit and then taking CS low will clear the READY/BUSY status from DO.

Vcc must be \geq 4.5V for proper operation of ERAL.

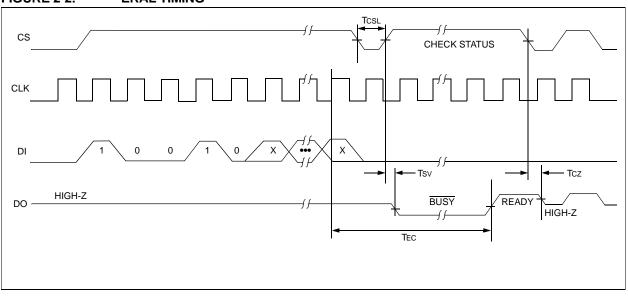
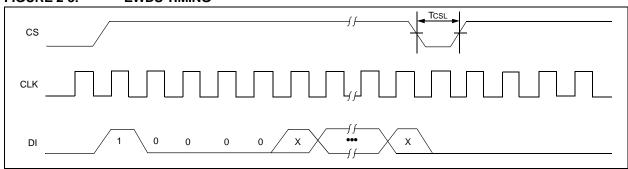


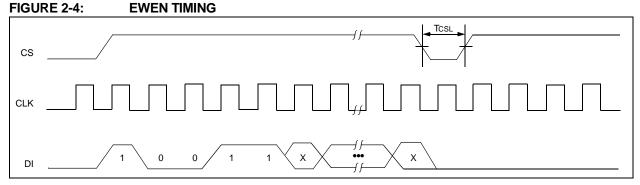
FIGURE 2-2: **ERAL TIMING**

2.6 ERASE/WRITE DISABLE And ENABLE (EWDS/EWEN)

The 93XX76A/B/C powers up in the ERASE/WRITE Disable (EWDS) state. All programming modes must be preceded by an ERASE/WRITE Enable (EWEN) instruction. Once the EWEN instruction is executed, programming remains enabled until an EWDS instruction is executed or VCC is removed from the device.

To protect against accidental data disturbance, the EWDS instruction can be used to disable all ERASE/ WRITE functions and should follow all programming operations. Execution of a READ instruction is independent of both the EWEN and EWDS instructions.





2.7 READ

The READ instruction outputs the serial data of the addressed memory location on the DO pin. A dummy zero bit precedes the 8-bit (If ORG pin is low or A-Version devices) or 16-bit (If ORG pin is high or B-version

devices) output string. The output data bits will toggle on the rising edge of the CLK and are stable after the specified time delay (TPD). Sequential read is possible when CS is held high. The memory data will automatically cycle to the next register and output sequentially.

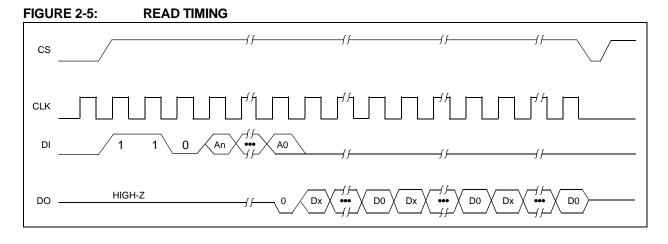
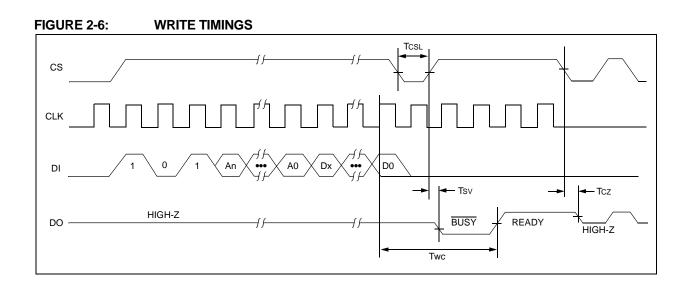


FIGURE 2-3: EWDS TIMING

2.8 WRITE

The WRITE instruction is followed by 8 bits (If ORG is low or A-version devices) or 16 bits (If ORG pin is high or B-version devices) of data which are written into the specified address. The self-timed auto-erase and programming cycle is initiated by the rising edge of CLK on the last data bit. The DO pin indicates the READY/BUSY status of the device, if CS is brought high after a minimum of 250 ns low (TCSL). DO at logical '0' indicates that programming is still in progress. DO at logical '1' indicates that the register at the specified address has been written with the data specified and the device is ready for another instruction.

Note: Issuing a Start bit and then taking CS low will clear the READY/BUSY status from DO.



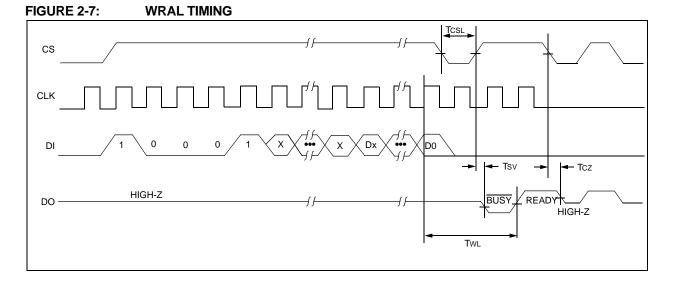
2.9 WRITE ALL (WRAL)

The Write All (WRAL) instruction will write the entire memory array with the data specified in the command. The self-timed auto-erase and programming cycle is initiated by the rising edge of CLK on the last data bit. Clocking of the CLK pin is not necessary after the device has entered the WRAL cycle. The WRAL command does include an automatic ERAL cycle for the device. Therefore, the WRAL instruction does not require an ERAL instruction but the chip must be in the EWEN status.

The DO pin indicates the READY/BUSY status of the device if CS is brought high after a minimum of 250 ns low (TCSL).

Note: Issuing a Start bit and then taking CS low will clear the READY/BUSY status from DO.

Vcc must be \geq 4.5V for proper operation of WRAL.



3.0 PIN DESCRIPTIONS

TABLE 3-1:PIN DESCRIPTIONS

Name	SOIC/PDIP/MSOP/ TSSOP	SOT-23	Function
CS	1	5	Chip Select
CLK	2	4	Serial Clock
DI	3	3	Data In
DO	4	1	Data Out
Vss	5	2	Ground
ORG	6	N/A	Organization / 93XX76C
PE	7	N/A	Program Enable
Vcc	8	6	Power Supply

3.1 Chip Select (CS)

A high level selects the device; a low level deselects the device and forces it into Standby mode. However, a programming cycle which is already in progress will be completed, regardless of the Chip Select (CS) input signal. If CS is brought low during a program cycle, the device will go into Standby mode as soon as the programming cycle is completed.

CS must be low for 250 ns minimum (TCSL) between consecutive instructions. If CS is low, the internal control logic is held in a Reset status.

3.2 Serial Clock (CLK)

The Serial Clock is used to synchronize the communication between a master device and the 93XX series device. Opcodes, address and data bits are clocked in on the positive edge of CLK. Data bits are also clocked out on the positive edge of CLK.

CLK can be stopped anywhere in the transmission sequence (at high or low-level) and can be continued anytime with respect to clock high time (TCKH) and clock low time (TCKL). This gives the controlling master freedom in preparing opcode, address and data.

CLK is a "don't care" if CS is low (device deselected). If CS is high, but the Start condition has not been detected (DI = 0), any number of clock cycles can be received by the device without changing its status (i.e., waiting for a Start condition).

CLK cycles are not required during the self-timed WRITE (i.e., auto ERASE/WRITE) cycle.

After detection of a Start condition the specified number of clock cycles (respectively low to high transitions of CLK) must be provided. These clock cycles are required to clock in all required opcode, address and data bits before an instruction is executed. CLK and DI then become don't care inputs waiting for a new Start condition to be detected.

3.3 Data In (DI)

Data In (DI) is used to clock in a Start bit, opcode, address and data synchronously with the CLK input.

3.4 Data Out (DO)

Data Out (DO) is used in the Read mode to output data synchronously with the CLK input (TPD after the positive edge of CLK).

This pin also provides READY/BUSY status information during ERASE and WRITE cycles. READY/BUSY status information is available on the DO pin if CS is brought high after being low for minimum Chip Select low time (TCSL) and an erase or write operation has been initiated.

The Status signal is not available on DO, if CS is held low during the entire ERASE or WRITE cycle. In this case, DO is in the HIGH-Z mode. If status is checked after the ERASE/WRITE cycle, the data line will be high to indicate the device is ready.

Note: Issuing a Start bit and then taking CS low will clear the READY/BUSY status from DO.

3.5 Organization (ORG)

When the ORG pin is connected to VCC or Logic HI, the (x16) memory organization is selected. When the ORG pin is tied to VSS or Logic LO, the (x8) memory organization is selected. For proper operation, ORG must be tied to a valid logic level.

93XX76A devices are always x8 organization and 93XX76B devices are always x16 organization.

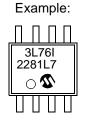
3.6 Program Enable (PE)

This pin allows the user to enable or disable the ability to write data to the memory array. If the PE pin is tied to Vcc, the device can be programmed. If the PE pin is tied to Vss, programming will be inhibited. PE is not available on 93XX76A or 93XX76B. On those devices, programming is always enabled. This pin cannot be floated, it must be tied to Vcc or Vss.

4.0 PACKAGING INFORMATION

4.1 Package Marking Information

8-Lead MSOP (150 mil)



Example:

ппп

Example:

93LC76

I/P 1L7

 \cap

Ш

10228

Ш

<u>п п п п</u>

4EL7

Ο

MSOP 1st Line Marking Codes						
Device	std mark	Pb-free mark				
93AA76C	3A76CT	GA76CT				
93LC76C	3L76CT	GL76CT				
93C76C	3C76CT	GC76CT				
T = blank for commercial, "I" for Industrial, "E" for Extended.						

SOT23 Marking Codes

Pb-free topside mark is same; Pb-free

I-temp

4BNN

4LNN

4ENN

4PNN

4HNN

4TNN

E-temp

4FNN

4RNN

4JNN

4UNN

Device

93AA76A

93AA76B

93LC76A

93LC76B

93C76A

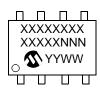
93C76B

noted only on carton label.

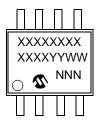
6-Lead SOT-23

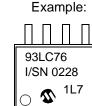
XXNN	
0	

8-Lead PDIP



8-Lead SOIC





TSSOP 1s	t Line Marl	king Codes
Device	std mark	Pb-free mark
93AA76C	A76C	GADC

8-Lead TSSOP

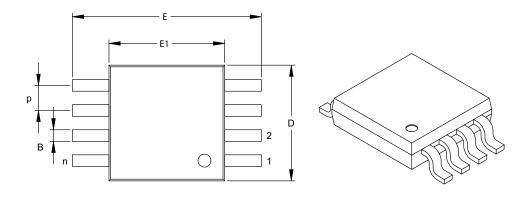


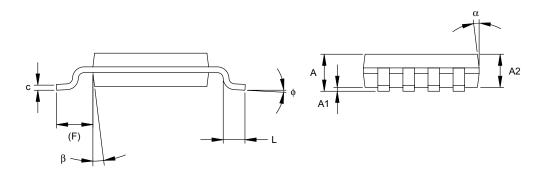
Example:

TSSOP 1st Line Marking Codes						
Device	std mark	Pb-free mark				
93AA76C	A76C	GADC				
93LC76C	L76C	GLDC				
93C76C C76C GCDC						
Temperature grad	Temperature grade is marked on line 2.					

Legend	: XXX	Part number
	Т	Temperature
	Blank	Commercial
	I	Industrial
	E	Extended
	ΥY	Year code (last 2 digits of calendar year) except TSSOP
		and MSOP which use only the last 1 digit
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
Note:	Custom m	arking available.

8-Lead Plastic Micro Small Outline Package (MS) (MSOP)





Units		INCHES		MILLIMETERS*		
mits	MIN	NOM	MAX	MIN	NOM	MAX
n		8			8	
р		.026 BSC		0.65 BSC		
A	-	-	.043	-	-	1.10
A2	.030	.033	.037	0.75	0.85	0.95
A1	.000	-	.006	0.00	-	0.15
E	.193 TYP.			4.90 BSC		
E1	.118 BSC			3.00 BSC		
D		.118 BSC		3.00 BSC		
L	.016	.024	.031	0.40	0.60	0.80
F		.037 REF		0.95 REF		
¢	0°	-	8°	0°	-	8°
С	.003	.006	.009	0.08	-	0.23
В	.009	.012	.016	0.22	-	0.40
α	5°	-	15°	5°	-	15°
β	5°	-	15°	5°	-	15°
	n p A A2 A1 E E1 D L F \$\overlineq\$ C B \$\alpha\$	MIN n p A A2 A30 A1 C000 E D L 0° c 0° B α	MIN NOM n 8 ρ .026 BSC A - A2 .030 A1 .000 E .193 TYP. E1 .118 BSC D .118 BSC L .016 .024 F .037 REF ϕ 0° - c .003 .006 B .009 .012 α 5° -	MIN NOM MAX n 8 ρ .026 BSC A - .043 A2 .030 .033 .037 A1 .000 - .006 E .193 TYP. .118 BSC D .118 BSC .031 F .037 REF .037 REF ϕ 0° - 8° c .003 .006 .009 B .009 .012 .016 α 5° - 15°	MIN NOM MAX MIN n 8 9 .026 BSC - A - - .043 - A2 .030 .033 .037 0.75 A1 .000 - .006 0.00 E .193 TYP. - .016 0.24 D .118 BSC - - .040 F .037 REF - - 8° 0° C .003 .006 .009 0.08 - B .009 .012 .016 0.22 α 5° - 15° 5°	MIN NOM MAX MIN NOM n 8 8 8 8 P .026 BSC 0.65 BSC 0.65 BSC A - .043 - - A2 .030 .033 .037 0.75 0.85 A1 .000 - .006 0.00 - E .193 TYP. 4.90 BSC 118 BSC 3.00 BSC D .118 BSC 3.00 BSC 3.00 BSC L .016 .024 .031 0.40 0.60 F .037 REF 0.95 REF 0.95 REF 0.95 REF ϕ 0° - 8° 0° - C .003 .006 .009 0.08 - B .009 .012 .016 0.22 - α 5° - 15° 5° -

*Controlling Parameter

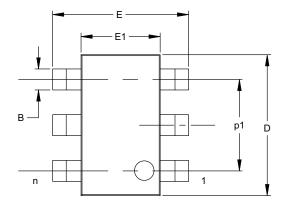
Notes:

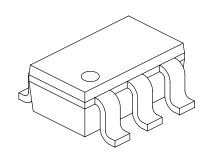
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

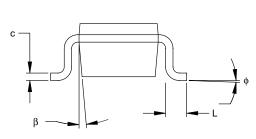
JEDEC Equivalent: MO-187

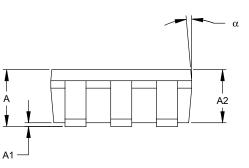
Drawing No. C04-111

6-Lead Plastic Small Outline Transistor (OT) (SOT-23)









Limits n p	MIN	NOM	MAX	MIN	NOM		
				IVIIIN	NOM	MAX	
р	1	6			6		
		.038			0.95		
p1		.075			1.90		
А	.035	.046	.057	0.90	1.18	1.45	
A2	.035	.043	.051	0.90	1.10	1.30	
A1	.000	.003	.006	0.00	0.08	0.15	
Е	.102	.110	.118	2.60	2.80	3.00	
E1	.059	.064	.069	1.50	1.63	1.75	
D	.110	.116	.122	2.80	2.95	3.10	
L	.014	.018	.022	0.35	0.45	0.55	
¢	0	5	10	0	5	10	
с	.004	.006	.008	0.09	0.15	0.20	
В	.014	.017	.020	0.35	0.43	0.50	
α	0	5	10	0	5	10	
	E E1 D L ¢ C B	E .102 E1 .059 D .110 L .014 φ 0 c .004 B .014	E .102 .110 E1 .059 .064 D .110 .116 L .014 .018 φ 0 .5 c .004 .006 B .014 .017	E .102 .110 .118 E1 .059 .064 .069 D .110 .116 .122 L .014 .018 .022 φ 0 5 10 c .004 .006 .008 B .014 .017 .020	E .102 .110 .118 2.60 E1 .059 .064 .069 1.50 D .110 .116 .122 2.80 L .014 .018 .022 0.35 φ 0 5 10 0 c .004 .006 .008 0.09 B .014 .017 .020 0.35	E .102 .110 .118 2.60 2.80 E1 .059 .064 .069 1.50 1.63 D .110 .116 .122 2.80 2.95 L .014 .018 .022 0.35 0.45 φ 0 5 10 0 5 c .004 .006 .008 0.09 0.15 B .014 .017 .020 0.35 0.43	

*Controlling Parameter

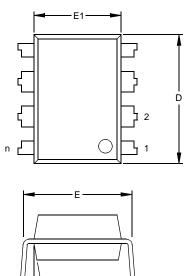
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

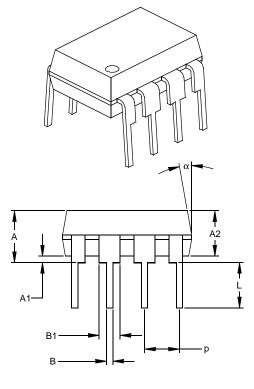
JEITA (formerly EIAJ) equivalent: SC-74A Drawing No. C04-120

8-Lead Plastic Du8-Lead Plastic Small Outline (al In-line (P) – 300 mil (PDIP)

С



eВ



Units		INCHES*		MILLIMETERS			
on Limits	MIN	NOM	MAX	MIN	NOM	MAX	
n		8			8		
р		.100			2.54		
А	.140	.155	.170	3.56	3.94	4.32	
A2	.115	.130	.145	2.92	3.30	3.68	
A1	.015			0.38			
E	.300	.313	.325	7.62	7.94	8.26	
E1	.240	.250	.260	6.10	6.35	6.60	
D	.360	.373	.385	9.14	9.46	9.78	
L	.125	.130	.135	3.18	3.30	3.43	
С	.008	.012	.015	0.20	0.29	0.38	
B1	.045	.058	.070	1.14	1.46	1.78	
В	.014	.018	.022	0.36	0.46	0.56	
§ eB	.310	.370	.430	7.87	9.40	10.92	
α	5	10	15	5	10	15	
β	5	10	15	5	10	15	
	on Limits n P A A2 A1 E E1 D L C B1 B § eB α	on Limits MIN n P A .140 A2 .115 A1 .015 E .300 E1 .240 D .360 L .125 c .008 B1 .045 § eB .310 α 5	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	on Limits MIN NOM MAX n 8 P .100 A .140 .155 A2 .115 .130 A1 .015 .170 A2 .115 .130 .145 A1 .015	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	

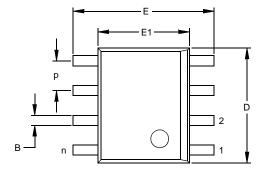
* Controlling Parameter § Significant Characteristic

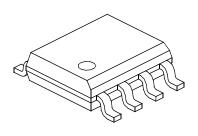
Notes:

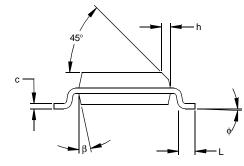
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-001

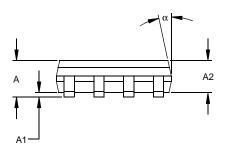
Drawing No. C04-018

8-Lead Plastic Small Outline (SN) - Narrow, 150 mil (SOIC)









	Units		INCHES*		MILLIMETERS		
Dimensio	on Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	А	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	E	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	¢	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

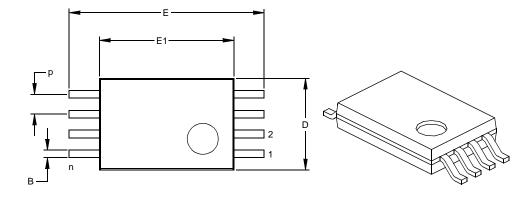
* Controlling Parameter § Significant Characteristic

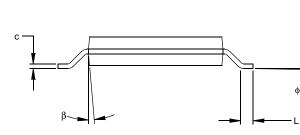
Notes:

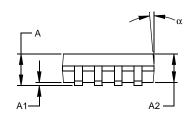
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-012

Drawing No. C04-057

8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)







	Units		INCHES		MILLIMETERS*		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.026			0.65	
Overall Height	А			.043			1.10
Molded Package Thickness	A2	.033	.035	.037	0.85	0.90	0.95
Standoff §	A1	.002	.004	.006	0.05	0.10	0.15
Overall Width	Е	.246	.251	.256	6.25	6.38	6.50
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50
Molded Package Length	D	.114	.118	.122	2.90	3.00	3.10
Foot Length	L	.020	.024	.028	0.50	0.60	0.70
Foot Angle	¢	0	4	8	0	4	8
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20
Lead Width	В	.007	.010	.012	0.19	0.25	0.30
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

* Controlling Parameter

§ Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side. JEDEC Equivalent: MO-153

Drawing No. C04-086

DS21796D-page 18

APPENDIX A: REVISION HISTORY

Revision C

Corrections to Section 1.0, Electrical Characteristics. Section 4.1, 6-Lead SOT-23 package to OT.

Revision D

Corrections to Device Selection Table, Table 1-1, Table 1-2, Section 2.4, Section 2.5, Section 2.8 and Section 2.9. Added note to Figure 2-7.

NOTES:

ON-LINE SUPPORT

Microchip provides on-line support on the Microchip World Wide Web site.

The web site is used by Microchip as a means to make files and information easily available to customers. To view the site, the user must have access to the Internet and a web browser, such as Netscape[®] or Microsoft[®] Internet Explorer. Files are also available for FTP download from our FTP site.

Connecting to the Microchip Internet Web Site

The Microchip web site is available at the following URL:

www.microchip.com

The file transfer site is available by using an FTP service to connect to:

ftp://ftp.microchip.com

The web site and file transfer site provide a variety of services. Users may download files for the latest Development Tools, Data Sheets, Application Notes, User's Guides, Articles and Sample Programs. A variety of Microchip specific business information is also available, including listings of Microchip sales offices, distributors and factory representatives. Other data available for consideration is:

- Latest Microchip Press Releases
- Technical Support Section with Frequently Asked Questions
- Design Tips
- Device Errata
- Job Postings
- Microchip Consultant Program Member Listing
- Links to other useful web sites related to Microchip Products
- Conferences for products, Development Systems, technical information and more
- · Listing of seminars and events

SYSTEMS INFORMATION AND UPGRADE HOT LINE

The Systems Information and Upgrade Line provides system users a listing of the latest versions of all of Microchip's development systems software products. Plus, this line provides information on how customers can receive the most current upgrade kits. The Hot Line Numbers are:

1-800-755-2345 for U.S. and most of Canada, and

1-480-792-7302 for the rest of the world.

042003

READER RESPONSE

It is our intention to provide you with the best documentation possible to ensure successful use of your Microchip product. If you wish to provide your comments on organization, clarity, subject matter, and ways in which our documentation can better serve you, please FAX your comments to the Technical Publications Manager at (480) 792-4150.

Please list the following information, and use this outline to provide us with your comments about this document.

To:	Technical Publications Manager	Total Pages Sent
RE:	Reader Response	
Fror	n: Name	
	Company	
	Address	
	City / State / ZIP / Country	
	Telephone: ()	FAX: ()
Арр	lication (optional):	
Wou	Ild you like a reply?YN	
Dev	ice: 93AA76A/B/C, 93LC76A/B/C, 93C76A	/B/C Literature Number: DS21796D
Que	stions:	
1.	What are the best features of this documen	t?
2.	How does this document meet your hardwa	are and software development needs?
۰ ۲	Do you find the organization of this docume	ant ecou to follow? If not why?
3.	Do you find the organization of this docume	ant easy to follow? If hot, why?
-		
4.	What additions to the document do you thin	k would enhance the structure and subject?
5.	What deletions from the document could be	e made without affecting the overall usefulness?
6.	Is there any incorrect or misleading informa	tion (what and where)?
-		
_		
7.	How would you improve this document?	
•		
-		

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	¥	<u>×</u>	<u>/xx</u>	¥		Ex	camples:
Device ⁻	Tape & Reel	 Temperature Range	Package	Lead Fin	ish	a)	EEPROM, MSOP package, 1.8V
						b)	93AA76AT-I/OT: 8K, 1024x8 Serial EEPROM, SOT-23 package, tape and reel, 1.8V
Device	93AA76B	:: 8K 1.8V Microv :: 8K 1.8V Microv :: 8K 1.8V Microv	wire Serial EE	PROM (x16)		c)	93AA76CT-I/MS: 8K, 1024x8 or 512x16 Serial EEPROM, MSOP package, tape and reel, 1.8V
		: 8K 2.5V Microv				a)	
		: 8K 2.5V Microv : 8K 2.5V Microv				b)	
	93C76A: 93C76B: 93C76C:		vire Serial EE	PROM (x16)		c)	SOT-23 package, tape and reel, 2.5V 93LC76CXT-I/SNG: 8K, 1024x8 or 512x16 Serial EEPROM, SOIC package, Industrial temperature, tape and reel, Pb-free finish, 2.5V
「ape & Reel:	Blank = T =					a) b)	EEPROM, MSOP package, 5.0V
Temperature Rang	ge I = E =	-40°C to +85 -40°C to +12					
Package	MS = OT = P = SN = ST =	SOT-23, 6-le Plastic DIP (Plastic SOIC	P (Micro Sma ad (Tape & R 300 mil body) 3 (150 mil bod ad	teel only) , 8-lead	ead)		
ead Finish:	Blank = G =		% / 37% SnP te Tin - Pure				
	6 =	Po-nee (Mat	le fin - Pure	311)			

Sales and Support

Data Sheets

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

- 1. Your local Microchip sales office
- 2. The Microchip Corporate Literature Center U.S. FAX: (480) 792-7277
- 3. The Microchip Worldwide Site (www.microchip.com)

Please specify which device, revision of silicon and Data Sheet (include Literature #) you are using.

New Customer Notification System

Register on our web site (www.microchip.com/cn) to receive the most current information on our products.

NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is intended through suggestion only and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. No representation or warranty is given and no liability is assumed by Microchip Technology Incorporated with respect to the accuracy or use of such information, or infringement of patents or other intellectual property rights arising from such use or otherwise. Use of Microchip's products as critical components in life support systems is not authorized except with express written approval by Microchip. No licenses are conveyed, implicitly or otherwise, under any intellectual property rights.

Trademarks

The Microchip name and logo, the Microchip logo, Accuron, dsPIC, KEELOQ, MPLAB, PIC, PICmicro, PICSTART, PRO MATE and PowerSmart are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

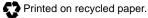
AmpLab, FilterLab, microID, MXDEV, MXLAB, PICMASTER, SEEVAL, SmartShunt and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Application Maestro, dsPICDEM, dsPICDEM.net, dsPICworks, ECAN, ECONOMONITOR, FanSense, FlexROM, fuzzyLAB, In-Circuit Serial Programming, ICSP, ICEPIC, microPort, Migratable Memory, MPASM, MPLIB, MPLINK, MPSIM, PICkit, PICDEM, PICDEM.net, PICtail, PowerCal, PowerInfo, PowerMate, PowerTool, rfLAB, rfPIC, Select Mode, SmartSensor, SmartTel and Total Endurance are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

Serialized Quick Turn Programming (SQTP) is a service mark of Microchip Technology Incorporated in the U.S.A.

All other trademarks mentioned herein are property of their respective companies.

© 2004, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.



QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV ISO/TS 16949:2002

Microchip received ISO/TS-16949:2002 quality system certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona and Mountain View, California in October 2003. The Company's quality system processes and procedures are for its PICmicro® 8-bit MCUs, KEELoo® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



WORLDWIDE SALES AND SERVICE

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: 480-792-7627

Web Address: http://www.microchip.com

Atlanta

3780 Mansell Road, Suite 130 Alpharetta, GA 30022 Tel: 770-640-0034 Fax: 770-640-0307

Boston

2 Lan Drive, Suite 120 Westford, MA 01886 Tel: 978-692-3848 Fax: 978-692-3821

Chicago

333 Pierce Road, Suite 180 Itasca, IL 60143 Tel: 630-285-0071 Fax: 630-285-0075

Dallas

4570 Westgrove Drive, Suite 160 Addison, TX 75001 Tel: 972-818-7423 Fax: 972-818-2924

Detroit

Tri-Atria Office Building 32255 Northwestern Highway, Suite 190 Farmington Hills, MI 48334 Tel: 248-538-2250 Fax: 248-538-2260

Kokomo

2767 S. Albright Road Kokomo, IN 46902 Tel: 765-864-8360 Fax: 765-864-8387

Los Angeles 18201 Von Karman, Suite 1090 Irvine, CA 92612 Tel: 949-263-1888 Fax: 949-263-1338

San Jose 1300 Terra Bella Avenue Mountain View, CA 94043 Tel: 650-215-1444 Fax: 650-961-0286

Toronto 6285 Northam Drive, Suite 108 Mississauga, Ontario L4V 1X5, Canada Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Australia Suite 22, 41 Rawson Street Epping 2121, NSW Australia Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing

Unit 706B Wan Tai Bei Hai Bldg. No. 6 Chaoyangmen Bei Str. Beijing, 100027, China Tel: 86-10-85282100 Fax: 86-10-85282104 China - Chengdu

Rm. 2401-2402, 24th Floor, Ming Xing Financial Tower No. 88 TIDU Street Chengdu 610016, China Tel: 86-28-86766200 Fax: 86-28-86766599

China - Fuzhou

Unit 28F, World Trade Plaza No. 71 Wusi Road Fuzhou 350001, China Tel: 86-591-7503506 Fax: 86-591-7503521

China - Hong Kong SAR

Unit 901-6, Tower 2, Metroplaza 223 Hing Fong Road Kwai Fong, N.T., Hong Kong Tel: 852-2401-1200 Fax: 852-2401-3431

China - Shanghai

Room 701, Bldg. B Far East International Plaza No. 317 Xian Xia Road Shanghai, 200051 Tel: 86-21-6275-5700 Fax: 86-21-6275-5060

China - Shenzhen

Rm. 1812, 18/F, Building A, United Plaza No. 5022 Binhe Road, Futian District Shenzhen 518033. China Tel: 86-755-82901380 Fax: 86-755-8295-1393

China - Shunde

Room 401, Hongjian Building, No. 2 Fengxiangnan Road, Ronggui Town, Shunde District, Foshan City, Guangdong 528303, China Tel: 86-757-28395507 Fax: 86-757-28395571 China - Qingdao

Rm. B505A, Fullhope Plaza, No. 12 Hong Kong Central Rd. Qingdao 266071, China

Tel: 86-532-5027355 Fax: 86-532-5027205 India **Divyasree Chambers** 1 Floor, Wing A (A3/A4) No. 11, O'Shaugnessey Road Bangalore, 560 025, India Tel: 91-80-2290061 Fax: 91-80-2290062 Japan

Benex S-1 6F 3-18-20, Shinyokohama Kohoku-Ku, Yokohama-shi Kanagawa, 222-0033, Japan Tel: 81-45-471- 6166 Fax: 81-45-471-6122

Korea

168-1, Youngbo Bldg. 3 Floor Samsung-Dong, Kangnam-Ku Seoul, Korea 135-882 Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934 Singapore 200 Middle Road #07-02 Prime Centre Singapore, 188980 Tel: 65-6334-8870 Fax: 65-6334-8850 Taiwan Kaohsiung Branch 30F - 1 No. 8 Min Chuan 2nd Road Kaohsiung 806, Taiwan Tel: 886-7-536-4818 Fax: 886-7-536-4803 Taiwan Taiwan Branch 11F-3, No. 207 Tung Hua North Road Taipei, 105, Taiwan Tel: 886-2-2717-7175 Fax: 886-2-2545-0139

EUROPE

Austria Durisolstrasse 2 A-4600 Wels Austria Tel: 43-7242-2244-399 Fax: 43-7242-2244-393 Denmark **Regus Business Centre** Lautrup hoj 1-3 Ballerup DK-2750 Denmark Tel: 45-4420-9895 Fax: 45-4420-9910 France Parc d'Activite du Moulin de Massy 43 Rue du Saule Trapu

Batiment A - ler Etage 91300 Massy, France Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany

Steinheilstrasse 10 D-85737 Ismaning, Germany Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Italy

Via Quasimodo, 12 20025 Legnano (MI) Milan, Italy

Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands

P. A. De Biesbosch 14 NL-5152 SC Drunen, Netherlands Tel: 31-416-690399 Fax: 31-416-690340 United Kingdom 505 Eskdale Road Winnersh Triangle

Wokingham Berkshire, England RG41 5TU Tel: 44-118-921-5869 Fax: 44-118-921-5820

01/26/04